

C8051F330-GDI 25 MIPS, 8 kB Flash, 10-Bit DAC, 10-Bit ADC **MCU Die in Wafer Form**

Analog Peripherals

10-Bit ADC

- Programmable throughput up to 200 ksps
- Up to 16 external inputs; programmable as sin-
- gle-ended or differential Reference from internal $V_{\text{REF}}, V_{\text{DD}},$ or external pin
- Internal or external start of conversion sources
- Built-in temperature sensor (±3 °C) 10-bit DAC (Current Mode)
- Comparator
 - Programmable hysteresis and response time
 - Configurable to generate interrupts or reset
- Low current $(0.4 \mu A)$

On-Chip Debug

- On-chip debug circuitry facilitates full speed, nonintrusive in-system debug (no emulator required)
- Provides breakpoints, single stepping, watchpoints
- Inspect/modify memory, registers, and stack

Supply Voltage: 2.7 to 3.6 V

- Typical operating current: 6.4 mA at 25 MHz 9 uA at 32 kHz

Typical stop mode current: <0.1 µA Temperature Range: -40 to +85 °C High-Speed 8051 µC Core

- Pipelined instruction architecture; executes 70% of instructions in 1 or 2 system clocks
- Up to 25 MIPS throughput with 25 MHz clock
- Expanded interrupt handler

Memory

- 768 bytes data RAM
- 8 kB Flash; in-system programmable in 512 byte sectors (512 bytes are reserved)

Digital Peripherals

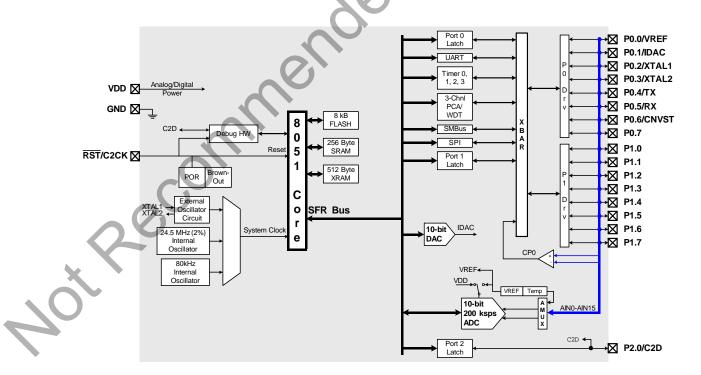
- 17 port I/O; all are 5 V tolerant
- Hardware SMBus[™] (I2C[™] compatible), SPI[™], and UART serial ports available concurrently
- Programmable 16-bit counter/timer array with three capture/compare modules, WDT
- 4 general-purpose 16-bit counter/timers
- Real-time clock mode using PCA or timer and external clock source

Clock Sources

- Two internal oscillators:
- 24.5 MHz, 2% accuracy supports UART operation
- 80 kHz low frequency, low-power
- External oscillator: Crystal, RC, C, or Clock (1 or 2 pin modes)
- Can switch between clock sources on-the-fly

Full Technical Data Sheet

C8051F330/1/2/3/4/5



1. Ordering Information

Ordering Part Number	MIPS (Peak)	Flash Memory (kB)*	RAM (Bytes)	SMBus/I ² C	UART	Enhanced SPI	Timers (16-bit)	Programmable Counter Array	Digital Port I/Os	10-bit 200 ksps ADC	Internal Voltage Reference	Temperature Sensor	Analog Comparators	Lead-free (RoHS Compliant)	Wafer Thickness
C8051F330-G1DI		8	768	1	1	1	4	► F	17	1			1	 ✓	28.5433 mil / 725 μm (No backgrind
C8051F330-GDI	25	8	768	1	1	1	4	~	17	Y	✓	~	1	✓	12 mil (backgrind)
		3	6	K											

Table 1.1. Product Selection Guide



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2. Pin Definitions

lame	Physical Pad Number	Туре	Description
V _{DD}	4,5		Power Supply Voltage.
GND	2,3		Ground.
RST/	6	D I/O	Device Reset. Open-drain output of internal POR or V_{DD} monitor. An external source can initiate a system reset by driving this pin low for at least 10 μ s.
C2CK		D I/O	Clock signal for the C2 Debug Interface.
P2.0/	7	D I/O	Port 2.0.
C2D		D I/O	Bi-directional data signal for the C2 Debug Interface.
P0.0/	1	D I/O or A In	Port 0.0.
VREF		A In	External VREF input.
P0.1	26	D I/O or A In	Port 0.1.
IDA0		AOut	IDA0 Output.
P0.2/	25	D I/O or A In	Port 0.2.
XTAL1		A In	External Clock Input. This pin is the external oscillator return for a crystal or resonator.
P0.3/	24	D I/O or A In	Port 0.3.
XTAL2	0	A I/O or D In	External Clock Output. For an external crystal or resonator, this pin is the excitation driver. This pin is the external clock input for CMOS, capacitor, or RC oscillator configurations.
P0.4	23	D I/O or A In	Port 0.4.
P0.5	22	D I/O or A In	Port 0.5.





Name	Physical Pad Number	Туре	Description
P0.6/	21	D I/O or A In	Port 0.6.
CNVSTR		D In	ADC0 External Convert Start or IDA0 Update Source Input.
P0.7	20	D I/O or A In	Port 0.7.
P1.0	18	D I/O or A In	Port 1.0.
P1.1	16	D I/O or A In	Port 1.1.
P1.2	15	D I/O or A In	Port 1.2.
P1.3	14	D I/O or A In	Port 1.3.
P1.4	11	D I/O or A In	Port 1.4.
P1.5	10	D I/O or A In	Port 1.5.
P1.6	9	D I/O or A In	Port 1.6.
P1.7	8	D I/O or A In	Port 1.7.

Table 2.1. Pin Definitions for the C8051F330-GDI	(Continued)*
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*Note: For a complete description of the functionality of all pins, refer to the C8051F330/1/2/3/4/5 technical data sheet.



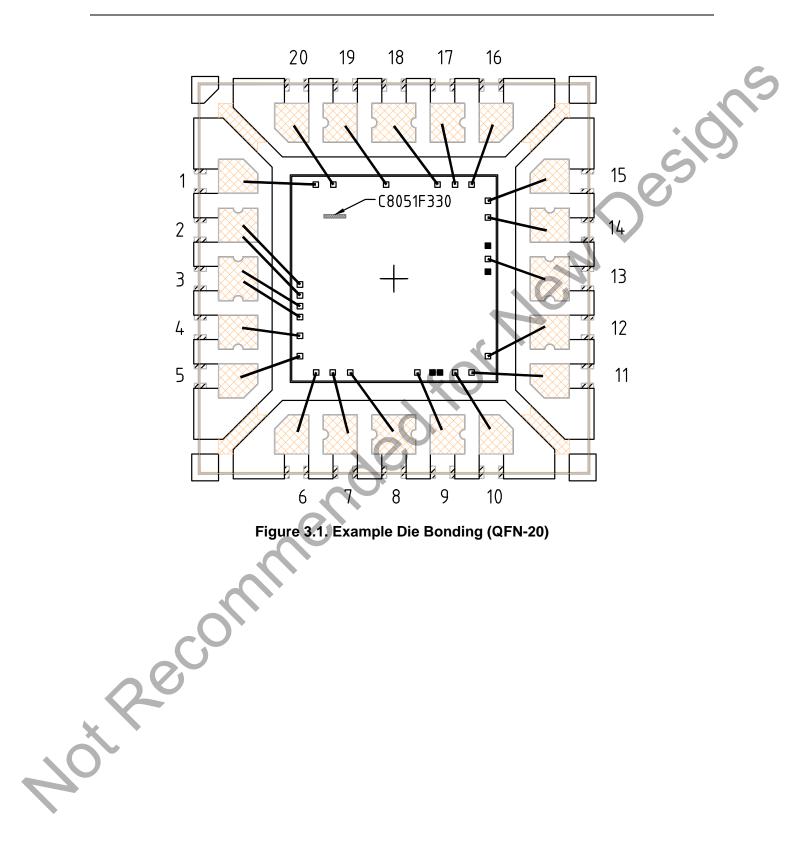
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3. Bonding Instructions

Physical Pad Number	Package Pin Number (20-QFN)	Package Pin Name	Physical Pad X (µm)	Physical Pad Y (µm)
1	P0.0	1	-802.7	964.7
2	GND	2	-964.7	-61.2
3	GND	2	-964.7	-173.2
4	VDD	3	-964.7	-284.1
5	VDD	3	-964.7	-396.1
6	/RST/C2CK	4	-964.7	-587.7
7	P2.0/C2D	5	-964.7	-797.7
8	P1.7	6	-797.7	-964.7
9	P1.6	7	-627.7	-964.7
10	P1.5	8	-447.7	-964.7
11	P1.4	9	240.7	-964.7
12	Reserved*	4	396.7	-964.7
13	Reserved*	\leftarrow	471.7	-964.7
14	P1.3	10	627.7	-964.7
15	P1.2	11	797.7	-964.7
16	P1.1	12	964.7	-797.7
17	Reserved*	-	964.7	70.05
18	P1.0	13	964.7	201.05
19	Reserved*	—	964.7	337.05
20	P0.7	14	964.7	627.7
21	P0.6	15	964.7	797.7
22	P0.5	16	797.7	964.7
23	P0.4	17	627.7	964.7
24	P0.3	18	447.7	964.7
25	P0.2	19	-79.9	964.7
26	P0.1	20	-622.7	964.7

Table 3.1. C8051F330-GDI Pad Connections

SILICON LABS





Wafer ID	C8051F330	C
Wafer Dimensions	8 in	
Die Dimensions	2.13 mm x 2.13 mm	
Wafer Thickness (no backgrind)	28.54 mil ±1 mil (725 μm)	SIS
Wafer Thickness (with backgrind)	12 mil ±1 mil	
Wafer Identification	Notch	
Scribe Line Width	80 µm	×
Die Per Wafer*	Contact Sales for info	
Passivation	Standard	
Wafer Packaging Detail	Wafer Jar	
Bond Pad Dimensions	60 µm x 60 µm	
Maximum Processing Temperature	250 °C	
Electronic Die Map Format	.txt	
Bond Pad Pitch Minimum	75 µm	
* Note: This is the Expected Known Good Die y the batch order quantity (one wafer).	ielded per wafer and represents	
NotRecommen		

Table 3.2. Wafer and Die Information



4. Wafer Storage Guidelines

It is necessary to conform to appropriate wafer storage practices to avoid product degradation or contamination.

- Wafers may be stored for up to 18 months in the original packaging supplied by Silicon Labs.
- Wafers must be stored at a temperature of 18–24 °C.
- n in or de Wafers must be stored in a humidity-controlled environment with a relative humidity of <30%.
 - Wafers should be stored in a clean, dry, inert atmosphere (e.g. nitrogen or clean, dry air).



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5. Failure Analysis (FA) Guidelines

Certain conditions must be met for Silicon Laboratories to perform Failure Analysis on devices sold in wafer form.

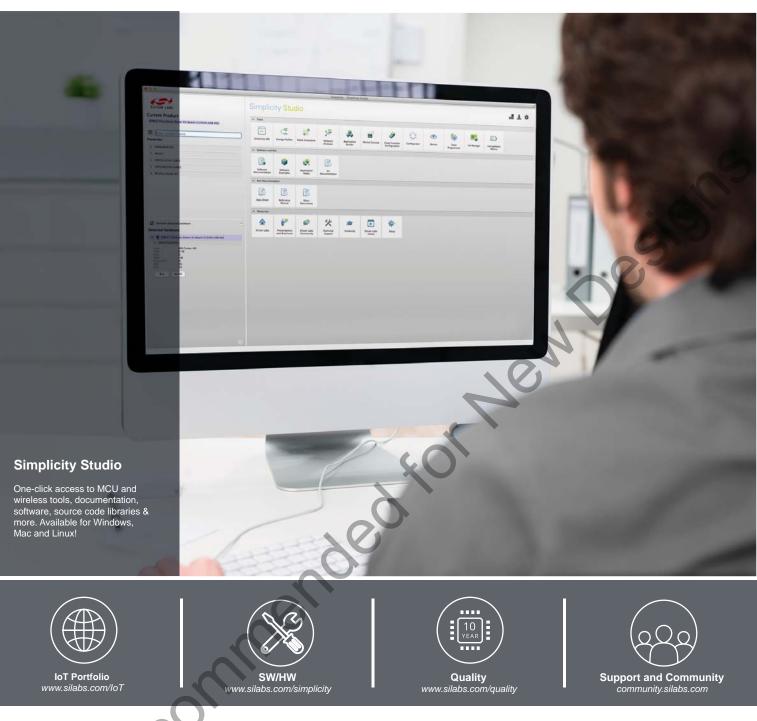
- In order to conduct failure analysis on a device in a customer-provided package, Silicon Laboratories must be provided with die assembled in an industry standard package that is pin compatible with existing packages Silicon Laboratories offers for the device. Initial response time for FA requests that meet this requirements will follow the standard FA guidelines for packaged parts.
- If retest of the entire wafer is requested, Silicon Laboratories must be provided with the whole econinended wafer. Silicon Laboratories cannot retest any wafers that have been sawed, diced, backgrind or are on tape. Initial response time for FA requests that meet this requirements will be 3 weeks.



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